



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



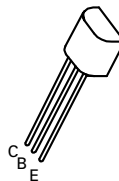
PNP SILICON PLANAR MEDIUM POWER HIGH GAIN TRANSISTOR

ZTX1151A

ISSUE 1 - JANUARY 1997

FEATURES

- * $V_{CE0} = -40V$
- * 3 Amp Continuous Current
- * 5 Amp Pulse Current
- * Low Saturation voltage
- * High Gain



E-Line
TO92 Compatible

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	-45	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Peak Pulse Current	I_{CM}	-5	A
Continuous Collector Current	I_C	-3	A
Base Current	I_B	-500	mA
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	1	W
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +200	$^{\circ}C$

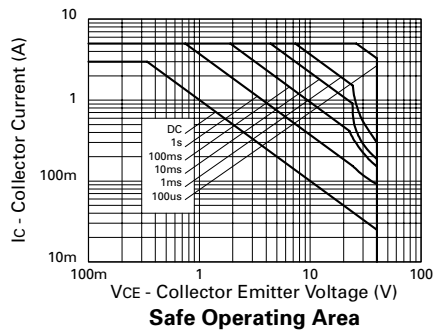
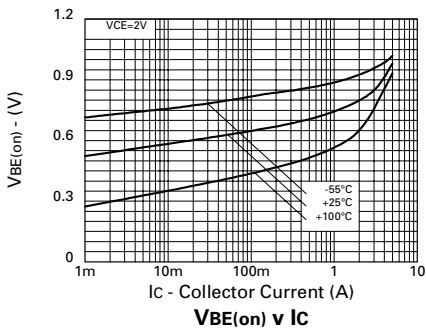
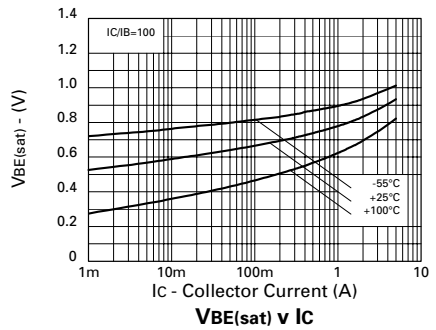
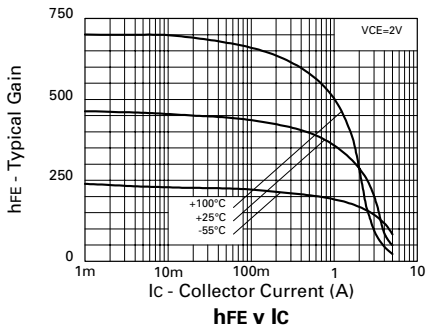
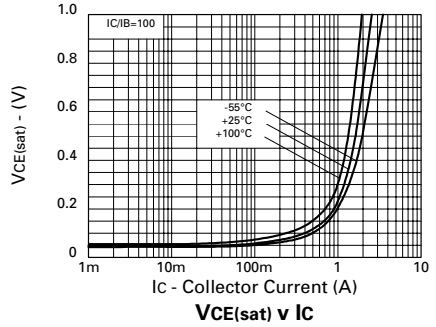
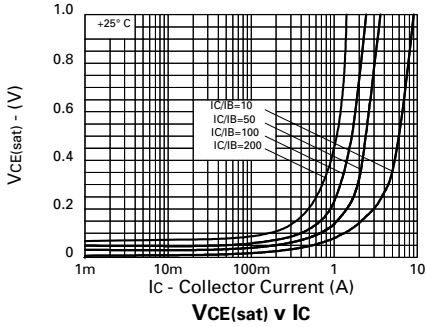
ZTX1151A

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

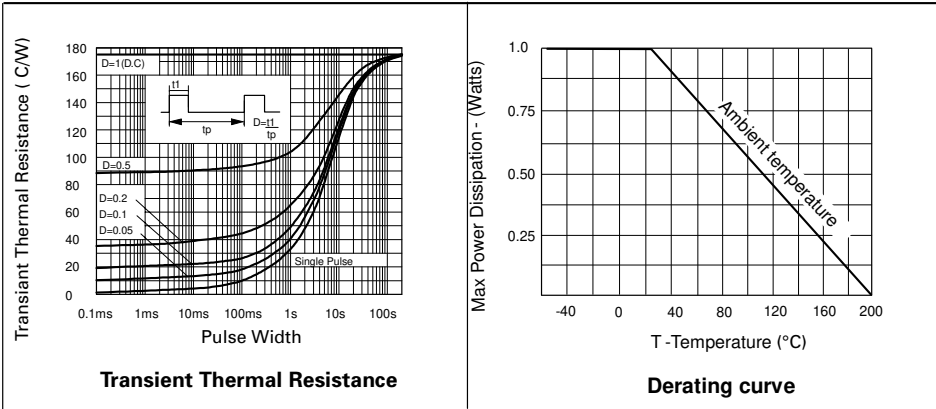
PARAMETER	SYMBOL	VALUE			UNIT	CONDITIONS.
		MIN.	TYP.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-45	-95		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CES}$	-40	-90		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-40	-85		V	$I_C = -10\text{mA}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEV}$	-40	-90		V	$I_C = -100\mu\text{A}$, $V_{EB} = +1\text{V}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	-8.5		V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	I_{CBO}		-0.3	-100	nA	$V_{CB} = -36\text{V}$
Emitter Cut-Off Current	I_{EBO}		-0.3	-100	nA	$V_{EB} = -4\text{V}$
Collector Emitter Cut-Off Current	I_{CES}		-0.3	-100	nA	$V_{CE} = -32\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-60 -115 -135 -160 -180	-90 -170 -210 -230 -240	mV mV mV mV mV	$I_C = -0.1\text{A}$, $I_B = -1.0\text{mA}^*$ $I_C = -0.5\text{A}$, $I_B = -5\text{mA}^*$ $I_C = -1\text{A}$, $I_B = -20\text{mA}^*$ $I_C = -1.8\text{A}$, $I_B = -70\text{mA}^*$ $I_C = -3\text{A}$, $I_B = -250\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-950	-1050	mV	$I_C = -3\text{A}$, $I_B = -250\text{mA}^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		-815	-950	mV	$I_C = -3\text{A}$, $V_{CE} = -2\text{V}^*$
Static Forward Current Transfer Ratio	h_{FE}	270 250 180 100	450 400 300 190 40	800		$I_C = -10\text{mA}$, $V_{CE} = -2\text{V}^*$ $I_C = -0.5\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -2\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -3\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -5\text{A}$, $V_{CE} = -2\text{V}^*$
Transition Frequency	f_T		145		MHz	$I_C = -50\text{mA}$, $V_{CE} = -10\text{V}$ $f = 50\text{MHz}$
Output Capacitance	C_{cb}		40		pF	$V_{CB} = -10\text{V}$, $f = 1\text{MHz}$
Switching Times	t_{on}		170		ns	$I_C = -2\text{A}$, $I_B = -20\text{mA}$, $V_{CC} = -30\text{V}$

ZTX1151A

TYPICAL CHARACTERISTICS



ZTX1151A



*ZETEX ZTX1151 Spice model Last revision 12/12/96

*

```
.MODEL      ZTX1151 PNP IS =1.7e-12 NF =1.004 ISE=1.02e-13 NE =1.55 BF =562
+          VAF=26.01 IKF=3.5 NR =.97 ISC= 1.5e-13 NC =1.3
+          BR =38 VAR=2.41 IKR=0.3 RE =25.37e-3 RB =250e-3
+          RC =25e-3 CJE=440e-12 CJC=160e-12 VJC=1.058
+          MJC= 0.5678 TF =0.8e-9 TR =55.5e-9
```

*

*

©1995 ZETEX PLC

The copyright in this model and the design embodied belong to Zetex PLC ("Zetex"). It is supplied free of charge by Zetex for the purpose of research and design and may be used or copied intact (including this notice) for that purpose only. All other rights are reserved. The model is believed accurate but no condition or warranty as to its merchantability or fitness for purpose is given and no liability in respect of any use is accepted by Zetex PLC, its distributors or agents.

Zetex plc.
Fields New Road, Chadderton, Oldham, OL9-8NP, United Kingdom.
Telephone: (44)161 622 4422 (Sales), (44)161 622 4444 (General Enquiries)
Fax: (44)161 622 4420

Zetex GmbH
Streitfeldstraße 19
D-81673 München
Germany
Telefon: (49) 89 45 49 49 0
Fax: (49) 89 45 49 49 49

Zetex Inc.
47 Mall Drive, Unit 4
Comack NY 11725
USA
Telephone: (516) 543-7100
Fax: (516) 864-7630

Zetex (Asia) Ltd.
3510 Metroplaza, Tower 2
Hing Fong Road,
Kwai Fong, Hong Kong
Telephone: (852) 26100 611
Fax: (852) 24250 494

These are supported by
agents and distributors in
major countries world-wide
©Zetex plc 1997

Internet: <http://www.zetex.com>

This publication is issued to provide outline information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contract or be regarded as a representation relating to the products or services concerned. The Company reserves the right to alter without notice the specification, design, price or conditions of supply of any product or service.